



ISL24111

9-Channel High Voltage TFT-LCD Logic Level Shifter with Gate Shaping Function

Key Features

- 9-Channel Logic Level Shifter
- 60V Operating Range ($V_{ONx} - V_{OFF}$)
- V_{ON1} [OUT1-OUT7] and V_{ON2} [OUT8, OUT9] Positive Power Supplies, V_{OFF} Negative Supply
- Gate Shaping Function with FCLK Input for Control
- +460mA and -730mA Peak Output Current for [OUT1-OUT7]
- 50ns Propagation Delay (Typical Low to High)
- 300ns Rise, 200ns Fall Time for [OUT1-OUT7]
- 520ns Rise, 350ns Fall Time for [OUT8-OUT9]
- Pb-Free (RoHS Compliant)
- 40°C to +85°C Ambient Operating Range

Description

The ISL24111 is a nine output channel high voltage TFT-LCD logic level shifter. The ISL24111 converts low power logic-level input timing signals, generated by the TFT-LCD timing controller (TCON), to high power level-shifted output signals used to drive a Gate-In-Panel (GIP) TFT-LCD. The high voltage level shifters can swing up to +60V, with peak output current of +460mA (source) and -730mA (sink).

The output channels are organized in two separate groups. Level shifter output channels OUT1 through OUT7 are powered from V_{ON1} and V_{OFF} (positive and negative supply voltage rails, respectively), while OUT8 and OUT9 output channels are powered from V_{ON2} and V_{OFF} . Each output features a low impedance output stage and achieves fast rise and fall times with minimal propagation delays. These features make the device ideal for driving highly capacitive loads in TFT-LCD applications.

The device features a gate shaping function that can be utilized to reduce overall LCD system power and improve image quality by reducing flicker. Outputs 1 through 6 can support gate shaping, while outputs 7 through 9 precisely track their respective input

The ISL24111 is available in a thermally enhanced 24 Ld 4x4mm TQFN package. It is specified for operation over the -40°C to +85°C extended ambient temperature range.

Applications

Logic Level Shifter

TFT-LCD TV, Monitor, Notebook, and Tablet

Gate-In-Panel (GIP)

Gate-On-Array (GOA)

Amorphous Silicon Gate (ASG)

Parameters

ISL24111

of Devices/ Channels

9

V_{OUT} (min) (V)

-54

V_{OUT} (max) (V)

60

Continuous Output Current

10 mA

Peak Output Current I_{PK}

25 A

Rise Time

300 ns

Fall Time

200 ns

Propagation Delay

50 ns

Capacitive Load Driving

5000 pF

I_S

4.5 mA

Operating Temp Range (°C)

-40 to +85